NSN 5961-01-037-0108

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View Online at https://aerobasegroup.com/nsn/5961-01-037-0108 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 emitter to base voltage, dc and 80.0 collector to base voltage, dc and 80.0 collector to emitter reverse voltage **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 81349-mils19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 81349-mil-s-19500/472 government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: